2N3904

ELECTRICAL CHARACTERISTICS (Values are at T_A = 25°C unless otherwise noted.)

| Symbol | Parametr | Conditions | Min | Max | Unit |
|----------------------|--|---|------|------|------|
| FF CHARACTER | RISTICS | • | • | • | ·• |
| V _{(BR)CEO} | Collector - Emitter Breakdown Voltage | $I_C = 1.0 \text{ mA}, I_B = 0$ | 40 | - | V |
| V _{(BR)CBO} | Collector - Base Breakdown Voltage | $I_C = 10 \mu A, I_E = 0$ | 60 | - | V |
| V _{(BR)EBO} | Emitter – Base Breakdown Voltage | $I_E = 10 \mu A, I_C = 0$ | 6.0 | - | V |
| I _{BL} | Base Cutoff Current | V _{CE} = 30 V, V _{EB} = 3 V | - | 50 | nA |
| I _{CEX} | Collector Cut-Off Current | V _{CE} = 30 V, V _{EB} = 3 V | - | 50 | nA |
| N CHARACTERI | STICS (Note 3) | | | | |
| h _{FE} | DC Current Gain | I _C = 0.1 mA, V _{CE} = 1.0 V | 40 | _ | - |
| | | I _C = 1.0 mA, V _{CE} = 1.0 V | 70 | - | |
| | | I _C = 10 mA, V _{CE} = 1.0 V | 100 | 300 | |
| | | $I_C = 50 \text{ mA}, V_{CE} = 1.0 \text{ V}$ | 60 | - | |
| | | I _C = 100 mA, V _{CE} = 1.0 V | 30 | - | |
| $V_{CE(sat)}$ | Collector - Emitter Saturation Voltage | I _C = 10 mA, I _B = 1.0 mA | - | 0.2 | V |
| | | $I_C = 50.0 \text{ mA}, I_B = 5.0 \text{ mA}$ | - | 0.3 | |
| $V_{BE(sat)}$ | Base - Emitter Saturation Voltage | I _C = 10.0 mA, I _B = 1.0 mA | 0.65 | 0.85 | V |
| | | $I_C = 50.0 \text{ mA}, I_B = 5.0 \text{ mA}$ | - | 0.95 | 1 |
| MALL-SIGNAL | CHARACTERISTICS | • | • | • | • |
| f _T | Current - Gain - Bandwidth Product | $I_C = 10 \text{ mA}, V_{CE} = 20 \text{ V},$ f = 100 MHz | 300 | _ | MHz |
| C_{obo} | Output Capacitance | V _{CB} = 5.0 V, I _E = 0, f = 100 kHz | _ | 4.0 | pF |
| C _{ibo} | Input Capacitance | V _{EB} = 0.5 V, I _C = 0, f = 100 kHz | _ | 8.0 | pF |
| NF | Noise Figure | I_{C} = 100 μ A, V_{CE} = 5.0 V, R_{S} = 1.0 k Ω , f = 10 Hz to 15.7 kHz | - | 5.0 | dB |
| WITCHING CHA | RACTERISTICS | • | _ | - | - |
| t _d | Delay Time | V _{CC} = 3.0 V, V _{BE} = 0.5 V, I _C = 10 mA, I _{B1} = 1.0 mA | - | 35 | ns |
| t _r | Rise Time | | - | 35 | ns |
| t _s | Storage Time | $V_{CC} = 3.0 \text{ V, } I_{C} = 10 \text{ mA,}$ $I_{B1} = I_{B2} = 1.0 \text{ mA}$ | - | 200 | ns |
| t _f | Fall Time | | _ | 50 | ns |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

3. Pulse Test: Pulse Width ≤ 300 μs; Duty Cycle ≤ 2%.

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TYPICAL PERFORMANCE CHARACTERISTICS

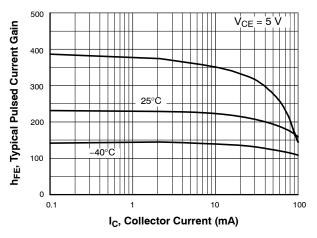


Figure 1. Typical Pulsed Current Gain vs. Collector Current

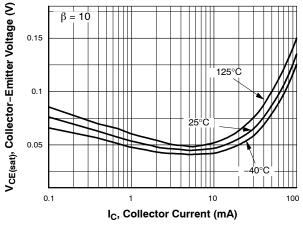


Figure 2. Collector-Emitter Saturation Voltage vs. Collector Current

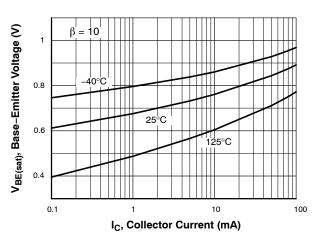


Figure 3. Base–Emitter Saturation Voltage vs. Collector Current

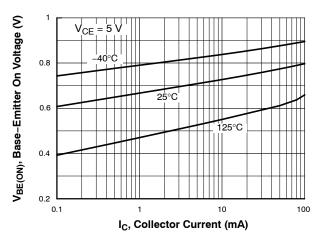


Figure 4. Base-Emitter On Voltage vs. Collector Current

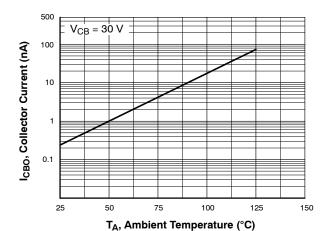


Figure 5. Collector Cut-Off Current vs. Ambient Temperature

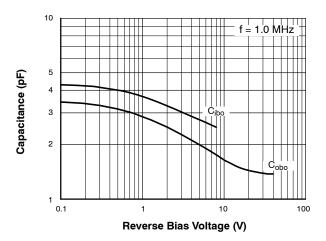


Figure 6. Capacitance vs. Reverse Bias Voltage

TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

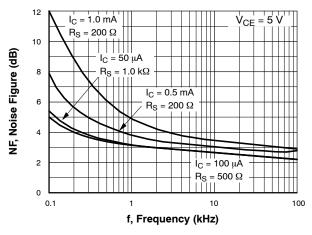


Figure 7. Noise Figure vs. Frequency

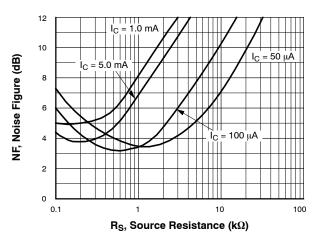


Figure 8. Noise Figure vs. Source Resistance

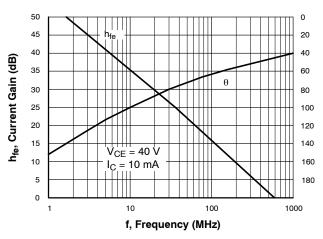


Figure 9. Current Gain and Phase Angle vs. Frequency

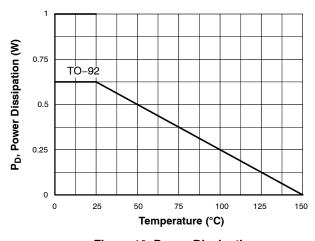


Figure 10. Power Dissipation vs. Ambient Temperature

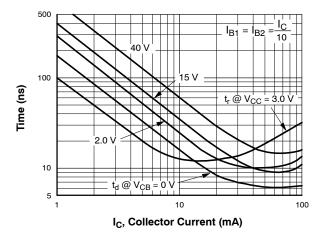


Figure 11. Turn-On Time vs. Collector Current

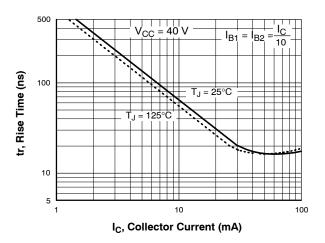


Figure 12. Rise Time vs. Collector Current

TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

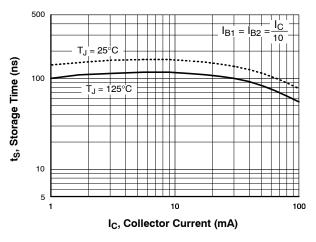


Figure 13. Storage Time vs. Collector Current

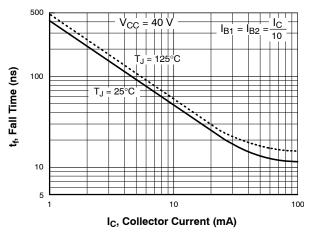


Figure 14. Fall Time vs. Collector Current

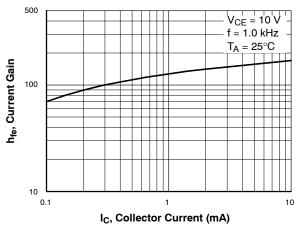


Figure 15. Current Gain

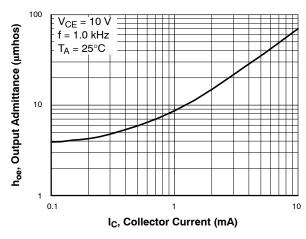


Figure 16. Output Admittance

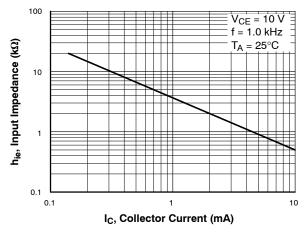


Figure 17. Input Impedance

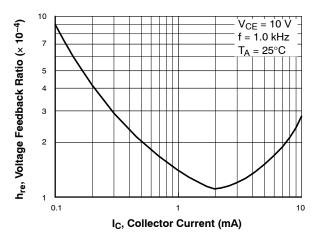


Figure 18. Voltage Feedback Ratio

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TEST CIRCUITS

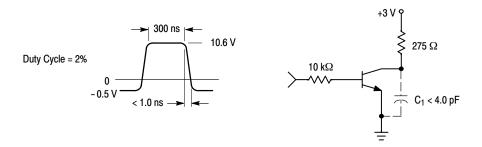


Figure 19. Delay and Rise Time Equivalent Test Circuit

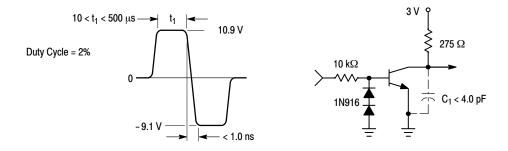


Figure 20. Storage and Fall Time Equivalent Test Circuit

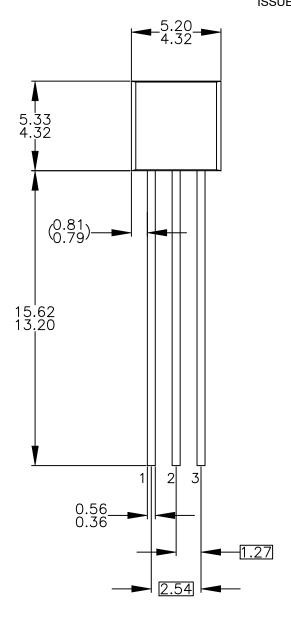
ORDERING INFORMATION

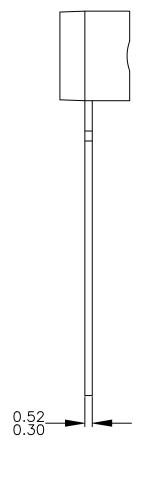
| Device | Package | Shipping [†] |
|-----------|-------------------------|--------------------------|
| 2N3904BU | TO-92-3 LF (Pb-Free) | 10000 Units / Bulk Bag |
| 2N3904TA | TO-92-3 LF (Pb-Free) | 2000 Units / Fan-Fold |
| 2N3904TAR | TO-92-3 LF (Pb-Free) | 2000 Units / Fan-Fold |
| 2N3904TF | TO-92-3 LF (Pb-Free) | 2000 Units / Tape & Reel |
| 2N3904TFR | TO-92-3 LF (Pb-Free) | 2000 Units / Tape & Reel |

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

TO-92 3 4.825x4.76 CASE 135AN ISSUE O

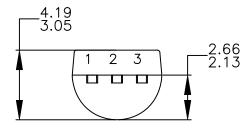
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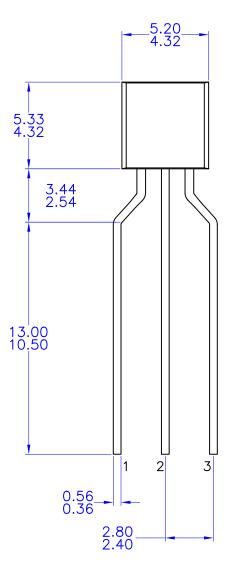
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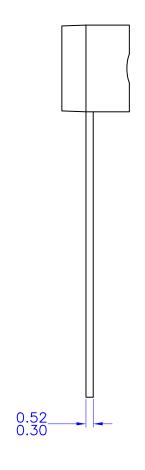
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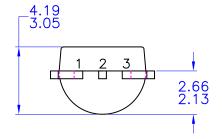
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